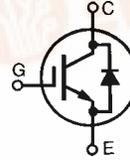




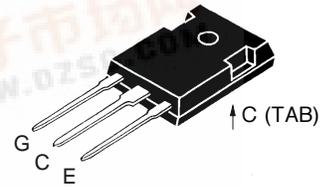
# HiPerFAST™ IGBT Lightspeed™ Series

IXGH 12N60CD1

$V_{CES} = 600 \text{ V}$   
 $I_{C25} = 24 \text{ A}$   
 $V_{CE(sat)} = 2.7 \text{ V}$   
 $t_{fi(typ)} = 55 \text{ ns}$



Symbol	Test Conditions	Maximum Ratings	TO-247 AD
$V_{CES}$	$T_J = 25^\circ\text{C to } 150^\circ\text{C}$	600 V	
$V_{CGR}$	$T_J = 25^\circ\text{C to } 150^\circ\text{C}; R_{GE} = 1 \text{ M}\Omega$	600 V	
$V_{GES}$	Continuous	$\pm 20 \text{ V}$	
$V_{GEM}$	Transient	$\pm 30 \text{ V}$	
$I_{C25}$	$T_C = 25^\circ\text{C}$	24 A	
$I_{C90}$	$T_C = 90^\circ\text{C}$	12 A	
$I_{CM}$	$T_C = 25^\circ\text{C}, 1 \text{ ms}$	48 A	
<b>SSOA (RBSOA)</b>	$V_{GE} = 15 \text{ V}, T_{VJ} = 125^\circ\text{C}, R_G = 33 \Omega$ Clamped inductive load, $L = 300 \mu\text{H}$	$I_{CM} = 24 \text{ A}$ @ $0.8 V_{CES}$	
$P_C$	$T_C = 25^\circ\text{C}$	100 W	
$T_J$		$-55 \dots +150 \text{ }^\circ\text{C}$	
$T_{JM}$		150 $^\circ\text{C}$	
$T_{stg}$		$-55 \dots +150 \text{ }^\circ\text{C}$	
$M_d$	Mounting torque with screw M3 Mounting torque with screw M3.5	0.45/4 Nm/lb.in. 0.55/5 Nm/lb.in.	
<b>Weight</b>		6 g	
Maximum lead temperature for soldering 1.6 mm (0.062 in.) from case for 10 s		300 $^\circ\text{C}$	



G = Gate, C = Collector,  
E = Emitter, TAB = Collector

### Features

- Very high frequency IGBT
- New generation HDMOS™ process
- International standard package JEDEC TO-247AD
- High peak current handling capability

### Applications

- PFC circuit
- AC motor speed control
- DC servo and robot drives
- Switch-mode and resonant-mode power supplies
- High power audio amplifiers

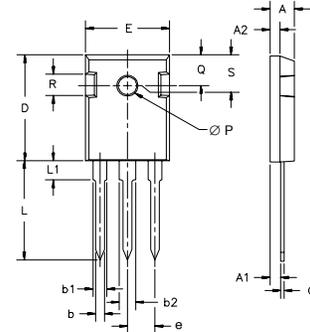
### Advantages

- Fast switching speed
- High power density

Symbol	Test Conditions	Characteristic Values ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)		
		min.	typ.	max.
$BV_{CES}$	$I_C = 250 \mu\text{A}, V_{GE} = 0 \text{ V}$	600		V
$V_{GE(th)}$	$I_C = 250 \mu\text{A}, V_{GE} = V_{GE}$	2.5		5.0 V
$I_{CES}$	$V_{CE} = 0.8 V_{CES}, T_J = 25^\circ\text{C}$ $V_{GE} = 0 \text{ V}, T_J = 125^\circ\text{C}$			200 $\mu\text{A}$ 1.5 mA
$I_{GES}$	$V_{CE} = 0 \text{ V}, V_{GE} = \pm 20 \text{ V}$			$\pm 100 \text{ nA}$
$V_{CE(sat)}$	$I_C = I_{CE90}, V_{GE} = 15 \text{ V}$	2.1	2.7	V



Symbol	Test Conditions	Characteristic Values ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)		
		min.	typ.	max.
$g_{fs}$	$I_C = I_{C90}$ ; $V_{CE} = 10\text{ V}$ , Pulse test, $t \leq 300\ \mu\text{s}$ , duty cycle $\leq 2\%$	5	11	S
$C_{ies}$	$V_{CE} = 25\text{ V}$ , $V_{GE} = 0\text{ V}$ , $f = 1\text{ MHz}$		860	pF
$C_{oes}$			100	pF
$C_{res}$			15	pF
$Q_g$	$I_C = I_{C90}$ , $V_{GE} = 15\text{ V}$ , $V_{CE} = 0.5 V_{CES}$		32	nC
$Q_{ge}$			10	nC
$Q_{gc}$			10	nC
$t_{d(on)}$	<b>Inductive load, <math>T_J = 25^\circ\text{C}</math></b> $I_C = I_{C90}$ , $V_{GE} = 15\text{ V}$ , $L = 300\ \mu\text{H}$ $V_{CE} = 0.8 V_{CES}$ , $R_G = R_{off} = 18\ \Omega$ Remarks: Switching times may increase for $V_{CE}$ (Clamp) $> 0.8 V_{CES}$ , higher $T_J$ or increased $R_G$		20	ns
$t_{ri}$			20	ns
$t_{d(off)}$			60	ns
$t_{fi}$			55	ns
$E_{off}$			0.09	mJ
$t_{d(on)}$	<b>Inductive load, <math>T_J = 125^\circ\text{C}</math></b> $I_C = I_{C90}$ , $V_{GE} = 15\text{ V}$ , $L = 300\ \mu\text{H}$ $V_{CE} = 0.8 V_{CES}$ , $R_G = R_{off} = 18\ \Omega$ Remarks: Switching times may increase for $V_{CE}$ (Clamp) $> 0.8 V_{CES}$ , higher $T_J$ or increased $R_G$		20	ns
$t_{ri}$			20	ns
$E_{on}$			0.5	mJ
$t_{d(off)}$			85	180 ns
$t_{fi}$			85	180 ns
$E_{off}$			0.27	0.60 mJ
$R_{thJC}$	IGBT			1.25 K/W
$R_{thCK}$		0.25		K/W

**TO-247 AD Outline**


Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.7	5.3	.185	.209
A <sub>1</sub>	2.2	2.54	.087	.102
A <sub>2</sub>	2.2	2.6	.059	.098
b	1.0	1.4	.040	.055
b <sub>1</sub>	1.65	2.13	.065	.084
b <sub>2</sub>	2.87	3.12	.113	.123
C	.4	.8	.016	.031
D	20.80	21.46	.819	.845
E	15.75	16.26	.610	.640
e	5.20	5.72	0.205	0.225
L	19.81	20.32	.780	.800
L1		4.50		.177
∅P	3.55	3.65	.140	.144
Q	5.89	6.40	0.232	0.252
R	4.32	5.49	.170	.216
S	6.15	BSC	.242	BSC

Symbol	Test Conditions	Characteristic Values ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)		
		min.	typ.	max.
$V_F$	$I_F = 15\text{ A}$ ; $T_{VJ} = 150^\circ\text{C}$ $T_{VJ} = 25^\circ\text{C}$		1.7	V
				2.5 V
$I_{RM}$	$V_R = 100\text{ V}$ ; $I_F = 25\text{ A}$ ; $-di_F/dt = 100\text{ A}/\mu\text{s}$ $L < 0.05\ \mu\text{H}$ ; $T_{VJ} = 100^\circ\text{C}$		2	2.5 A
$t_{rr}$		$I_F = 1\text{ A}$ ; $-di/dt = 50\text{ A}/\mu\text{s}$ ; $V_R = 30\text{ V}$ , $T_J = 25^\circ\text{C}$		35
$R_{thJC}$	Diode			1.6 K/W